Preferred Devices

Surface Mount Ultrafast Power Rectifiers

MURS105T3, MURS110T3, MURS115T3, MURS120T3, MURS140T3, MURS160T3

Ideally suited for high voltage, high frequency rectification, or as free wheeling and protection diodes in surface mount applications where compact size and weight are critical to the system.

Features

- Pb-Free Packages are Available
- Small Compact Surface Mountable Package with J-Bend Leads
- Rectangular Package for Automated Handling
- High Temperature Glass Passivated Junction
- Low Forward Voltage Drop (0.71 to 1.05 Volts Max @ 1.0 A, $T_J = 150$ °C)

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 95 mg (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Polarity: Polarity Band Indicates Cathode Lead



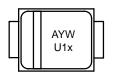
http://onsemi.com

ULTRAFAST RECTIFIERS 1.0 AMPERE 50-600 VOLTS



SMB CASE 403A

MARKING DIAGRAM



U1 = Device Code x A, B, C, D, G or J A = Assembley Location Y = Year

Y = Year W = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information in the table on page 2 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking table on page 2 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MAXIMUM RATINGS

		MURS						
Rating	Symbol	105T3	110T3	115T3	120T3	140T3	160T3	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	150	200	400	600	V
Average Rectified Forward Current	I _{F(AV)}	1.0 @ T _L = 155°C 2.0 @ T _L = 145°C				= 150°C = 125°C	Α	
Non-Repetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	IFSM	40		35		А		
Operating Junction Temperature	TJ	- 65 to +175				°C		

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Lead	$R_{ heta JL}$	13	°C/W
$(T_L = 25^{\circ}C)$			

ELECTRICAL CHARACTERISTICS

Maximum Instantaneous Forward Voltage (Note 1) $(i_F = 1.0 \text{ A}, T_J = 25^{\circ}\text{C})$ $(i_F = 1.0 \text{ A}, T_J = 150^{\circ}\text{C})$	VF	0.875 0.71	1.25 1.05	V
Maximum Instantaneous Reverse Current (Note 1) (Rated DC Voltage, T _J = 25°C) (Rated DC Voltage, T _J = 150°C)	İR	2.0 50	5.0 150	μΑ
Maximum Reverse Recovery Time $ \begin{aligned} (i_F = 1.0 \text{ A, di/dt} = 50 \text{ A/}\mu\text{s}) \\ (i_F = 0.5 \text{ A, } i_R = 1.0 \text{ A, } I_R \text{ to } 0.25 \text{ A}) \end{aligned} $	t _{rr}	35 25	75 50	ns
Maximum Forward Recovery Time (i _F = 1.0 A, di/dt = 100 A/μs, Rec. to 1.0 V)	t _{fr}	25	50	ns

^{1.} Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.

DEVICE MARKING AND ORDERING INFORMATION

Device	Marking	Package	Shipping [†]
MURS105T3	U1A	SMB	2500 Units/Tape & Reel
MURS110T3	U1B	SMB	2500 Units/Tape & Reel
MURS115T3	U1C	SMB	2500 Units/Tape & Reel
MURS120T3	U1D	SMB	2500 Units/Tape & Reel
MURS120T3G	U1D	SMB (Pb-Free)	2500 Units/Tape & Reel
MURS140T3	U1G	SMB	2500 Units/Tape & Reel
MURS140T3G	U1G	SMB (Pb-Free)	2500 Units/Tape & Reel
MURS160T3	U1J	SMB	2500 Units/Tape & Reel
MURS160T3G	U1J	SMB (Pb-Free)	2500 Units/Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MURS105T3, MURS110T3, MURS115T3, MURS120T3

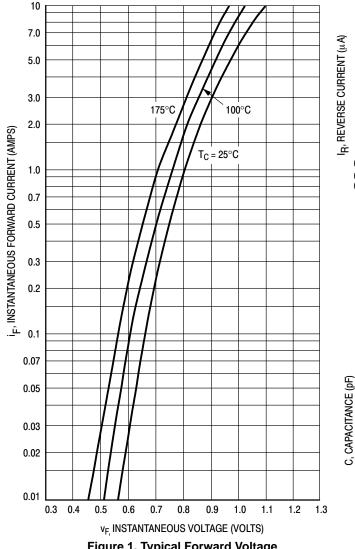


Figure 1. Typical Forward Voltage

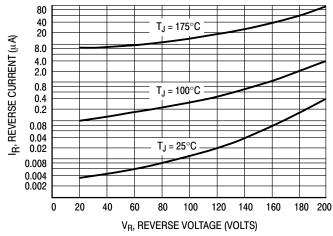


Figure 2. Typical Reverse Current*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if applied V_R is sufficiently below rated V_R.

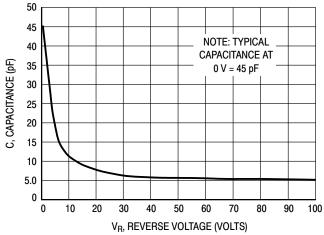


Figure 3. Typical Capacitance

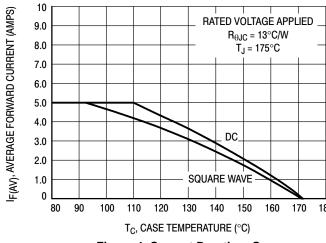


Figure 4. Current Derating, Case

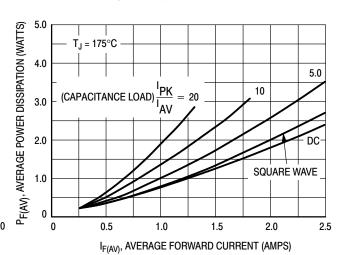
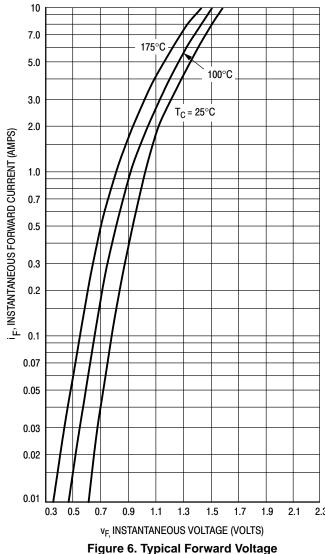


Figure 5. Power Dissipation

MURS140T3, MURS160T3



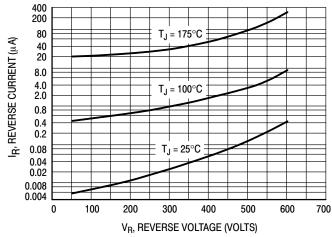


Figure 7. Typical Reverse Current*

* The curves shown are typical for the highest voltage device in the voltage grouping. Typical reverse current for lower voltage selections can be estimated from these same curves if applied V_R is sufficiently below rated V_R.

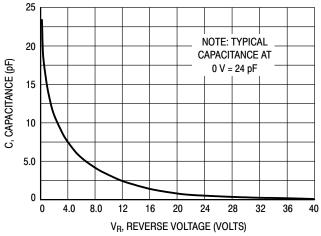


Figure 8. Typical Capacitance

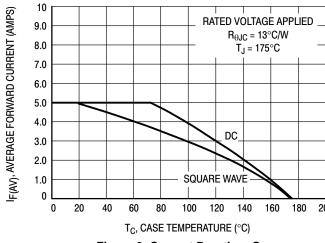


Figure 9. Current Derating, Case

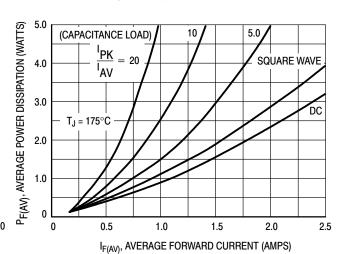
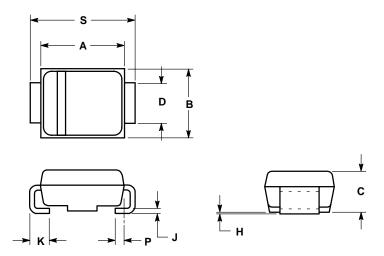


Figure 10. Power Dissipation

PACKAGE DIMENSIONS

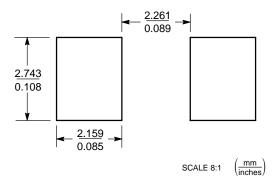
SMB DO-214AA CASE 403A-03 ISSUE D



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. D DIMENSION SHALL BE MEASURED WITHIN DIMENSION P.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.160	0.180	4.06	4.57	
В	0.130	0.150	3.30	3.81	
С	0.075	0.095	1.90	2.41	
D	0.077	0.083	1.96	2.11	
Н	0.0020	0.0060	0.051	0.152	
J	0.006	0.012	0.15	0.30	
K	0.030	0.050	0.76	1.27	
P	0.020	REF	0.51 REF		
S	0.205	0.220	5.21	5.59	

SOLDERING FOOTPRINT*



^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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